

PSMN1R4-40YLD

N-channel 40 V, 1.4 m Ω , 240 A logic level MOSFET in LFPAK56 using NextPower-S3 technology

14 March 2019

Product data sheet

1. General description

240 Amp, logic level gate drive N-channel enhancement mode MOSFET in 175 °C LFPAK56 package using advanced TrenchMOS Superjunction technology. This product has been designed and qualified for high performance power switching applications.

2. Features and benefits

- · 240 A capability
- Avalanche rated, 100% tested at I_{AS} = 190 A
- NextPower-S3 technology delivers 'superfast switching with soft recovery'
- · Low Q_{RR}, Q_G and Q_{GD} for high system efficiency and low EMI designs
- Schottky-Plus body-diode, gives soft switching without the associated high I_{DSS} leakage
- Optimised for 4.5 V gate drive utilising NextPower-S3 Superjunction technology
- High reliability LFPAK (Power SO8) package, copper-clip, solder die attach and qualified to 175 °C
- Exposed leads can be wave soldered, visual solder joint inspection and high quality solder joints
- Low parasitic inductance and resistance

3. Applications

- · Synchronous rectification
- DC-to-DC converters
- · High performance & high efficiency server power supply
- Motor control
- Power OR-ing

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	40	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	240	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	238	W
Tj	junction temperature			-55	-	175	°C
Static characte	ristics			•			
R _{DSon}	drain-source on-state resistance	$V_{GS} = 4.5 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ Fig. 10		-	1.38	1.85	mΩ
		$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ Fig. 10		-	1.12	1.4	mΩ
Dynamic characteristics							



Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Q_{GD}	gate-drain charge	$I_D = 25 \text{ A}; V_{DS} = 20 \text{ V}; V_{GS} = 4.5 \text{ V};$	-	13	26	nC
Q _{G(tot)}	total gate charge	Fig. 12; Fig. 13	-	45	65	nC

^{[1] 240}A continuous current has been successfully demonstrated during application test. Practically, the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	S	source	mb	D	
2	S	source	<u> </u>		
3	S	source		a	G—(F)
4	G	gate	0 0 0 0	mbb076 S	
mb	D	mounting base; connected to drain	1 2 3 4 LFPAK56; Power- SO8 (SOT669)		

6. Ordering information

Table 3. Ordering information

Type number	Package	ackage						
	Name	Description	Version					
PSMN1R4-40YLD	LFPAK56; Power-SO8	Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads	SOT669					

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN1R4-40YLD	1D440L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	40	V
V_{DSM}	peak drain-source voltage	$t_p \le 20 \text{ ns}; f \le 500 \text{ kHz}; E_{DS(AL)} \le 200 \text{ nJ};$ pulsed		-	45	V
V_{DGR}	drain-gate voltage	25 °C ≤ T_j ≤ 175 °C; R_{GS} = 20 kΩ		-	40	V
V_{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	238	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	240	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	214	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 3		-	1201	Α
T _{stg}	storage temperature			-55	175	°C

Symbol	Parameter	Conditions		Min	Max	Unit
Tj	junction temperature			-55	175	°C
$T_{sld(M)}$	peak soldering temperature			-	260	°C
V _{ESD}	electrostatic discharge voltage	НВМ		2	-	kV
Source-drain d	liode					
Is	source current	T _{mb} = 25 °C		-	198.6	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$		-	1201	А
Avalanche rug	gedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 74 A; V_{sup} ≤ 40 V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 0.23 ms	[2]	-	446	mJ
		I_D = 25 A; $V_{sup} \le 40$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 2.52 ms	[2]	-	1641	mJ
I _{AS}	non-repetitive avalanche current	$V_{sup} \le 40 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C};$ $R_{GS} = 50 \Omega$	[2]	-	190	Α

^{[1] 240}A continuous current has been successfully demonstrated during application test. Practically, the current will be limited by PCB, thermal design and operating temperature.

[2] Protected by 100% test

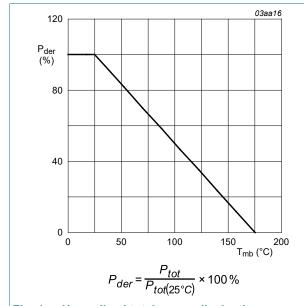
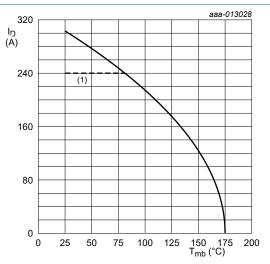


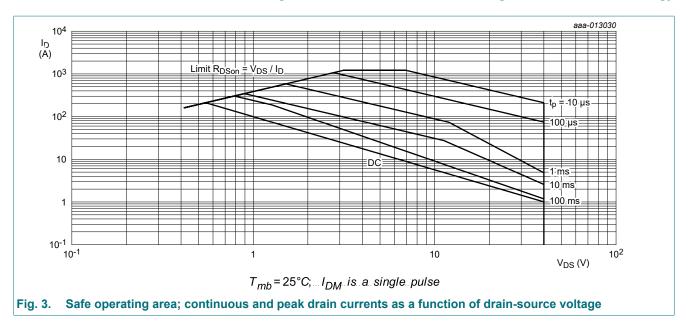
Fig. 1. Normalized total power dissipation as a function of mounting base temperature



(1) 240A Continuous current has been successfully demonstrate during application tests. Practically the current will be limited by PCB, thermal design and operation temperature.

V_{GS} ≥ 10 V

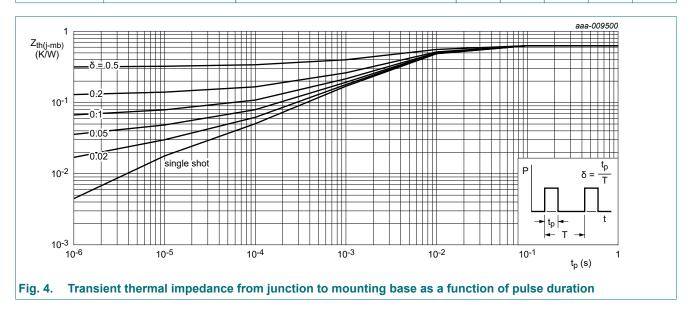
Fig. 2. Continuous drain current as a function of mounting base temperature



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4	-	0.56	0.63	K/W
R _{th(j-a)}		Fig. 5	-	50	-	K/W
junction to ambient	Fig. 6	-	125	-	K/W	



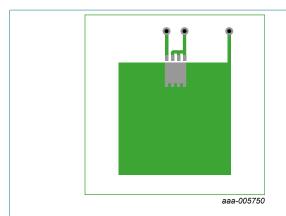


Fig. 5. PCB layout for thermal resistance junction to ambient 1" square pad; FR4 Board; 2oz copper

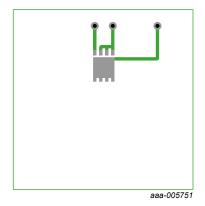


Fig. 6. PCB layout for thermal resistance junction to ambient minimum footprint;FR4 board; 2oz copper

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	cteristics					
V _{(BR)DSS} drain-source		$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	40	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	36	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.05	1.7	2.2	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-4.8	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 32 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μΑ
		V _{DS} = 32 V; V _{GS} = 0 V; T _j = 125 °C	-	12	-	μΑ
I _{GSS}	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 10	-	1.12	1.4	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 10; Fig. 11	-	-	2.65	mΩ
		V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C; Fig. 10	-	1.38	1.85	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 175 °C; Fig. 10; Fig. 11	-	-	3.4	mΩ
R _G	gate resistance	f = 1 MHz	-	1.1	3.43	Ω
Dynamic cha	aracteristics			'		
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 20 V; V _{GS} = 10 V; Fig. 12; Fig. 13	-	96	143	nC
		I _D = 25 A; V _{DS} = 20 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13	-	45	65	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V	-	85	-	nC
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 20 V; V _{GS} = 4.5 V;	-	15	25	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 12; Fig. 13	-	9	-	nC

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Q _{GS(th-pl)}	post-threshold gate- source charge			-	6	-	nC
Q _{GD}	gate-drain charge			-	13	26	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 20 V; <u>Fig. 12</u> ; <u>Fig. 13</u>		-	2.7	-	V
C _{iss}	input capacitance	$V_{DS} = 20 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$		-	6661	10413	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u>		-	1543	2309	pF
C _{rss}	reverse transfer capacitance			-	299	658	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 20 \text{ V}; R_L = 0.8 \Omega; V_{GS} = 4.5 \text{ V}; R_{G(ext)} = 5 \Omega$		-	39	-	ns
t _r	rise time			-	49	-	ns
t _{d(off)}	turn-off delay time			-	47	-	ns
t _f	fall time			-	30	-	ns
Q _{oss}	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 20 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}$		-	50	-	nC
Source-dra	in diode						
V_{SD}	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}; Fig. 15$		-	0.78	1.2	V
t _{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$		-	47	-	ns
Q _r	recovered charge	V _{DS} = 20 V; <u>Fig. 16</u>	[1]	-	61	-	nC
t _a	reverse recovery rise time			-	25.4	-	ns
t _b	reverse recovery fall time			-	21.7	-	ns

[1] includes capacitive recovery

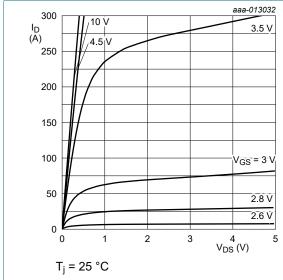


Fig. 7. Output characteristics; drain current as a function of drain-source voltage; typical values

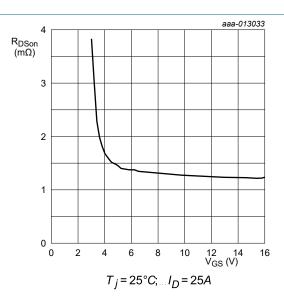


Fig. 8. Drain-source on-state resistance as a function of gate-source voltage; typical values

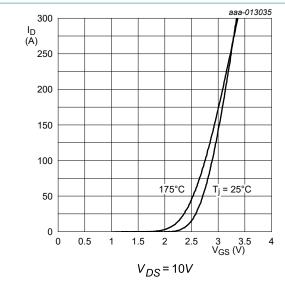


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

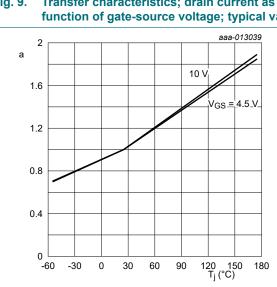


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

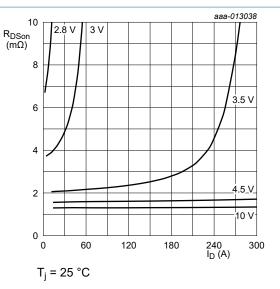


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values

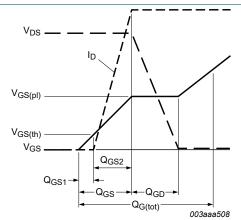


Fig. 12. Gate charge waveform definitions

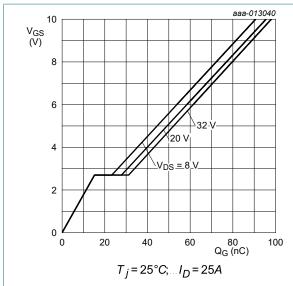


Fig. 13. Gate-source voltage as a function of gate charge; typical values

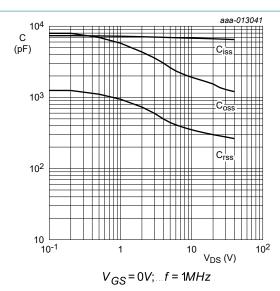


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

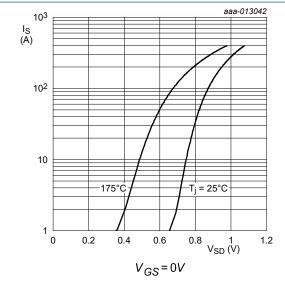


Fig. 15. Source current as a function of source-drain voltage; typical values

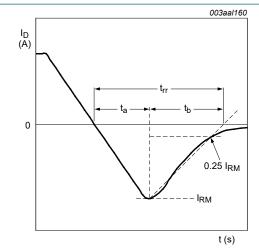
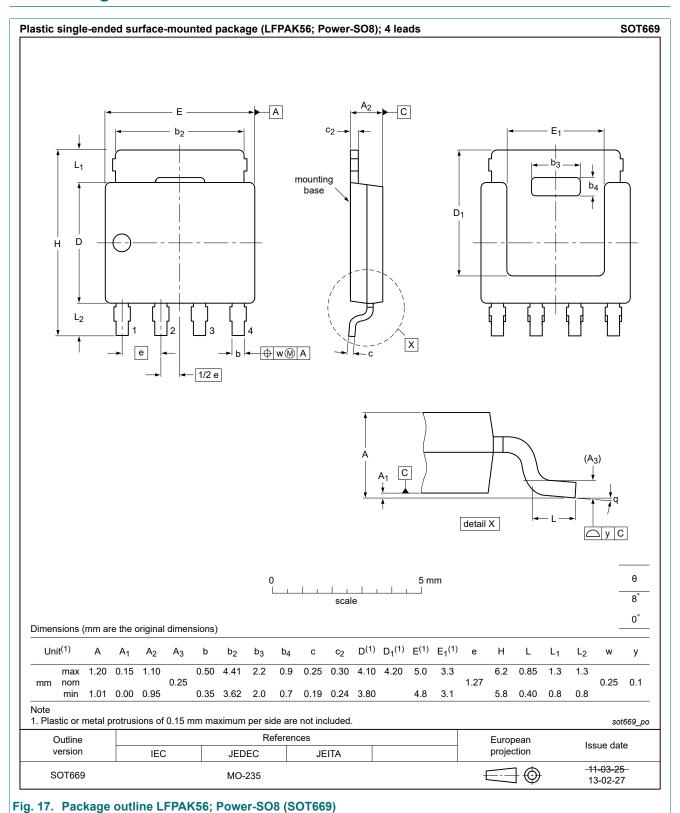
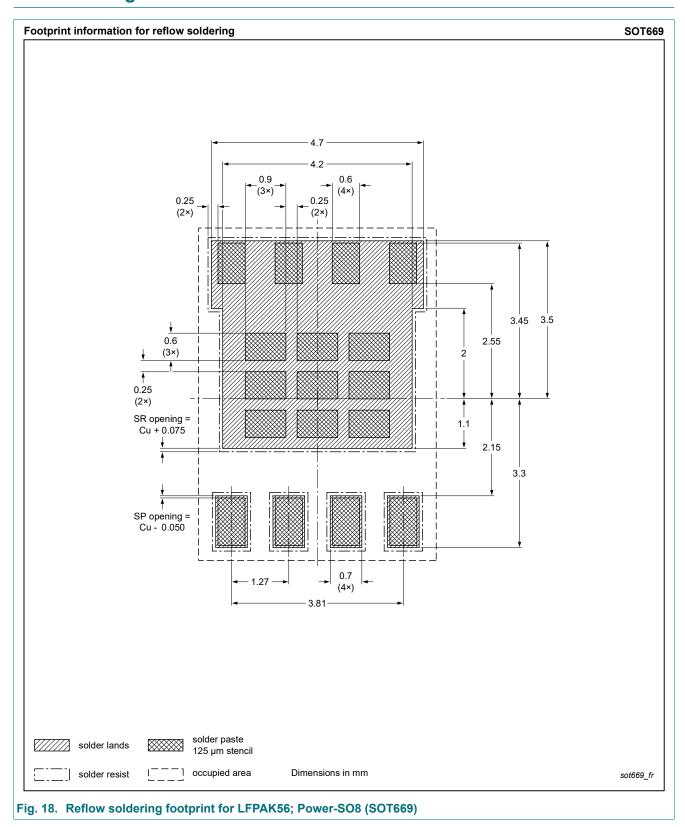


Fig. 16. Reverse recovery timing definition

11. Package outline



12. Soldering



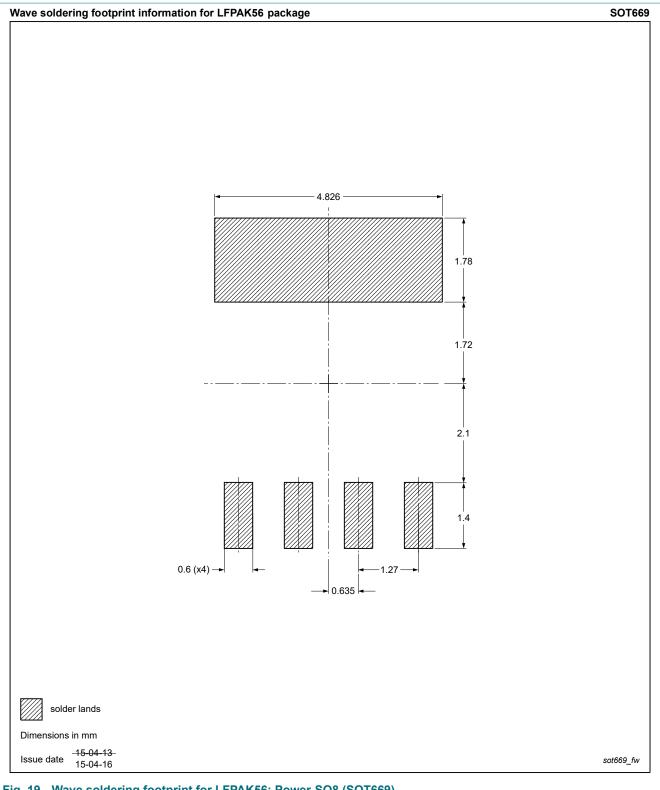


Fig. 19. Wave soldering footprint for LFPAK56; Power-SO8 (SOT669)

13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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